NEC

PHOTOCOUPLER

PS2765-1

HIGH ISOLATION VOLTAGE AC INPUT RESPONSE TYPE 4-PIN SOP PHOTOCOUPLER

–NEPOC™ Series–

DESCRIPTION

The PS2765-1 is an optically coupled isolator containing GaAs light emitting diodes and an NPN silicon phototransistor.

This package is mounted in a plastic SOP (Small Outline Package) for high density applications.

The package has shield effect to cut off ambient light.

FEATURES

- Isolation distance (0.4 mm MIN.)
- AC input response
- SOP (Small Outline Package) type
- High isolation voltage (BV = 3 750 Vr.m.s.)
- High-speed switching (t_r = 4 μs TYP., t_f = 5 μs TYP.)
- Ordering number of taping product: PS2765-1-F3, F4
- UL approved: File No. E72422 (S)
- BSI approved: No. 8436/8437

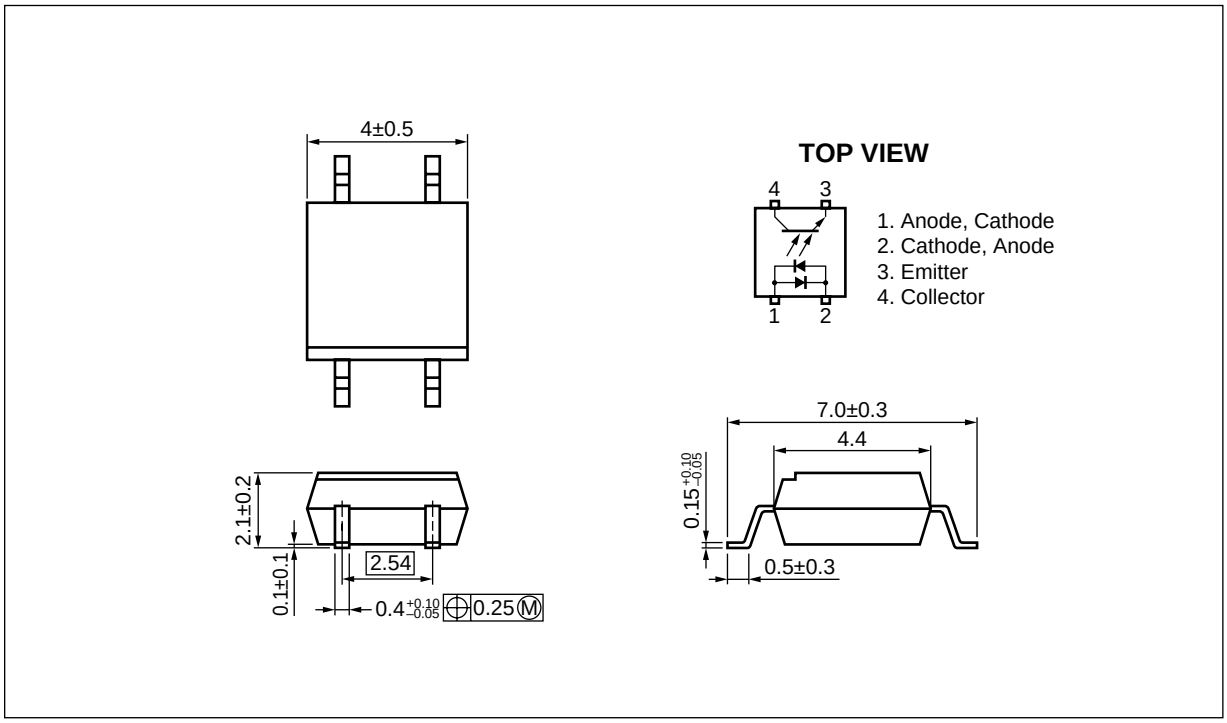
APPLICATIONS

- Hybrid IC
- Programmable logic controllers
- Power supply

Document No. P14145EJ3V0DS00 (3rd edition)
Date Published September 2000 NS CP (K)
Printed in Japan

The mark ★ shows major revised points.

PACKAGE DIMENSIONS (Unit: mm)



PHOTOCOUPLER CONSTRUCTION

Parameter	Unit (MIN.)
Air Distance	5 mm
Creepage Distance	5 mm
Isolation Distance	0.4 mm

ORDERING INFORMATION

Part Number	Package	Packing Style	Application Part Number*1
PS2765-1	4-pin SOP	Magazine case 100 pcs	PS2765-1
PS2765-1-F3		Embossed Tape 3 500 pcs/reel	
PS2765-1-F4			

***1** For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	I_F	± 50	mA
	Power Dissipation	P_D	80	mW
	Peak Forward Current*1	I_{FP}	± 1.0	A
Transistor	Collector to Emitter Voltage	V_{CEO}	40	V
	Emitter to Collector Voltage	V_{ECO}	5	V
	Collector Current	I_C	40	mA
	Power Dissipation Derating	ΔP_C/°C	1.5	mW/°C
	Power Dissipation	P_C	150	mW
Isolation Voltage*2		BV	3 750	Vr.m.s.
★ Operating Ambient Temperature		T_A	–55 to +100	°C
Storage Temperature		T_{stg}	–55 to +150	°C

***1** PW = 100 μs, Duty Cycle = 1 %

***2** AC voltage for 1 minute at T_A = 25 °C, RH = 60 % between input and output

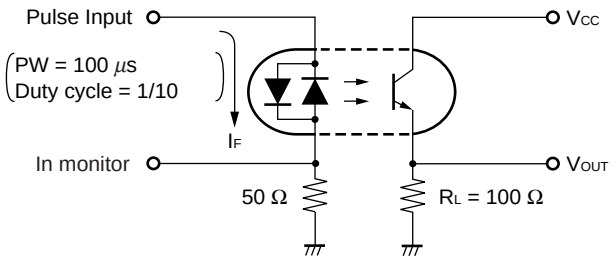
ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	V_F	I_F = ± 5 mA		1.1	1.4	V
	Terminal Capacitance	C_t	V = 0 V, f = 1 MHz		30		pF
Transistor	Collector to Emitter Dark Current	I_{CEO}	I_F = 0 mA, V_{CE} = 40 V			100	nA
Coupled	Current Transfer Ratio (I_C/I_F) *1	CTR	I_F = ± 5 mA, V_{CE} = 5 V	50	100	400	%
	Collector Saturation Voltage	$V_{CE (sat)}$	I_F = ± 10 mA, I_C = 2 mA			0.3	V
	Isolation Resistance	R_{I-O}	V_{I-O} = 1 kV_{DC}	10^{11}			Ω
	Isolation Capacitance	C_{I-O}	V = 0 V, f = 1 MHz		0.4		pF
	Rise Time*2	t_r	V_{CC} = 5 V, I_C = 2 mA, R_L = 100 Ω		4		μs
	Fall Time*2	t_f			5		

***1** CTR rank

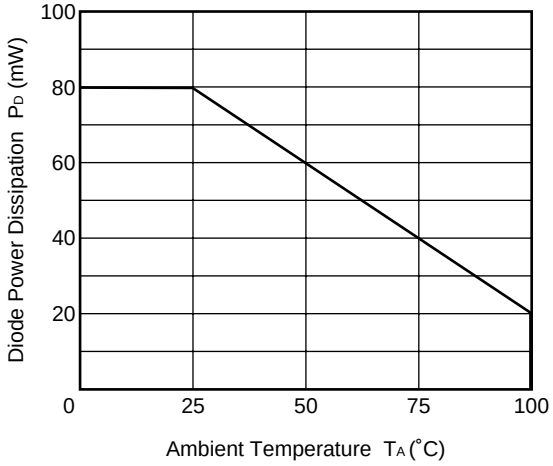
N: 50 to 400 (%)

***2** Test circuit for switching time

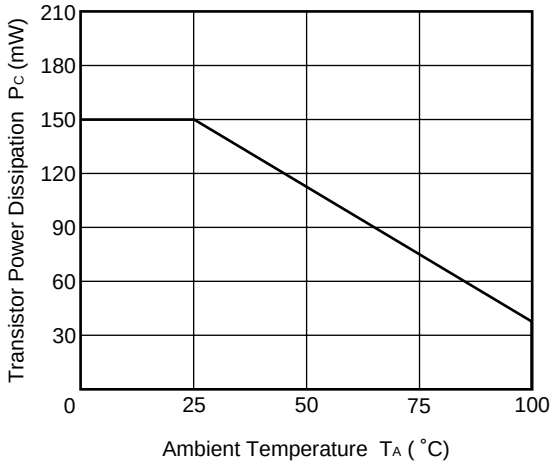


TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise specified)

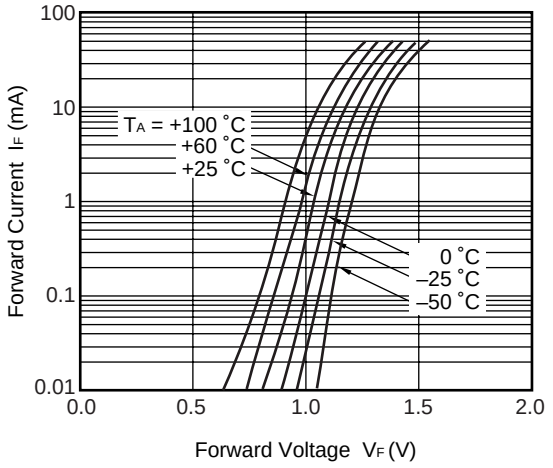
DIODE POWER DISSIPATION vs. AMBIENT TEMPERATURE



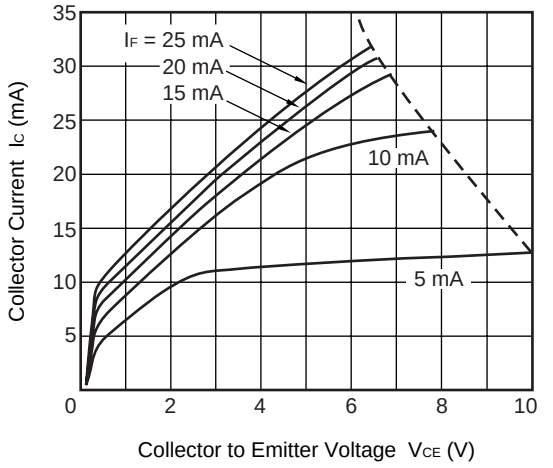
TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



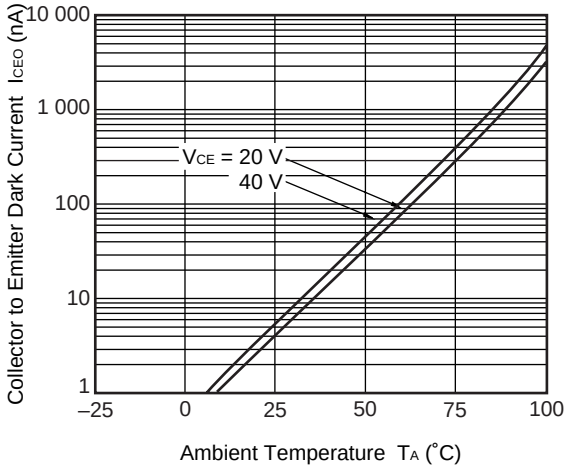
FORWARD CURRENT vs. FORWARD VOLTAGE



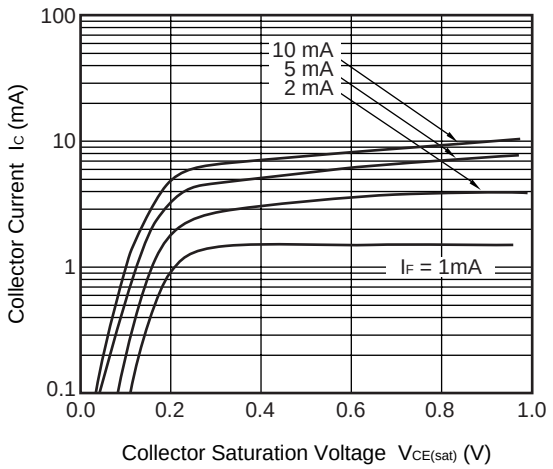
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



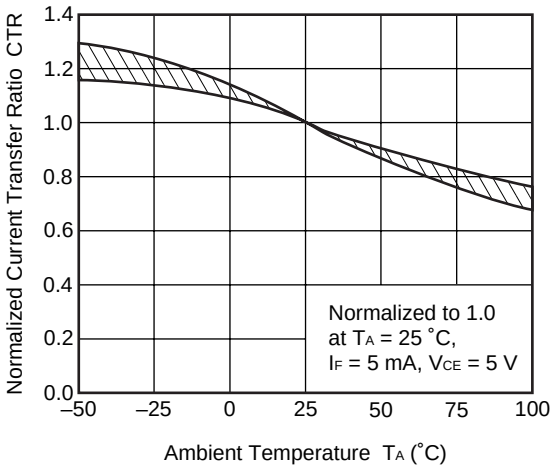
COLLECTOR TO EMITTER DARK CURRENT vs. AMBIENT TEMPERATURE



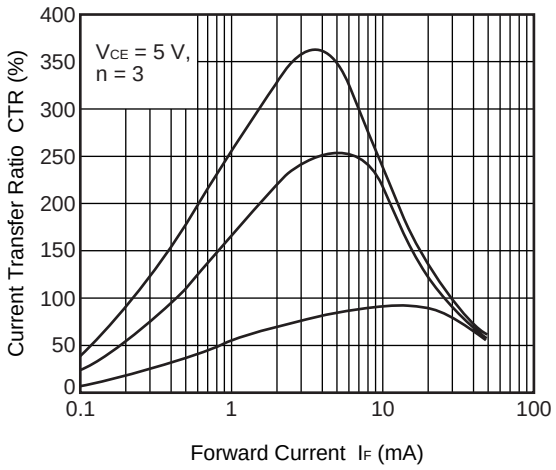
COLLECTOR CURRENT vs. COLLECTOR SATURATION VOLTAGE



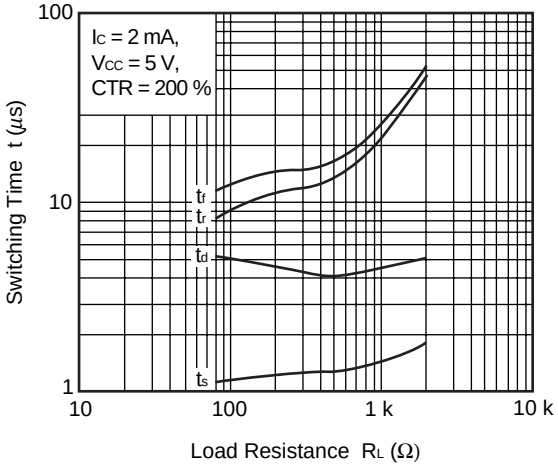
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



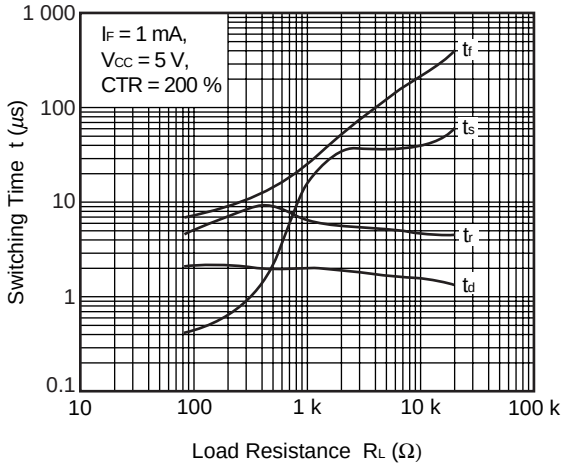
CURRENT TRANSFER RATIO vs. FORWARD CURRENT



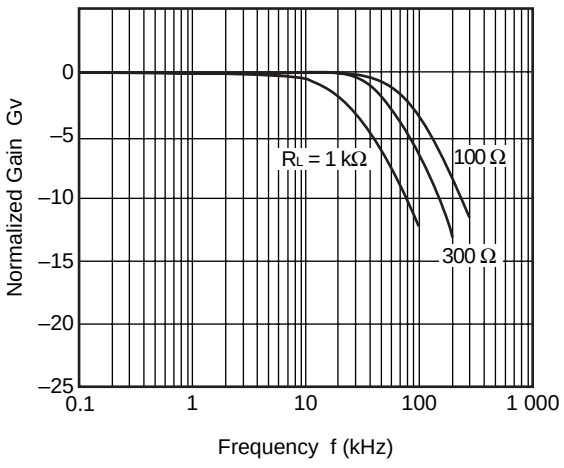
SWITCHING TIME vs. LOAD RESISTANCE



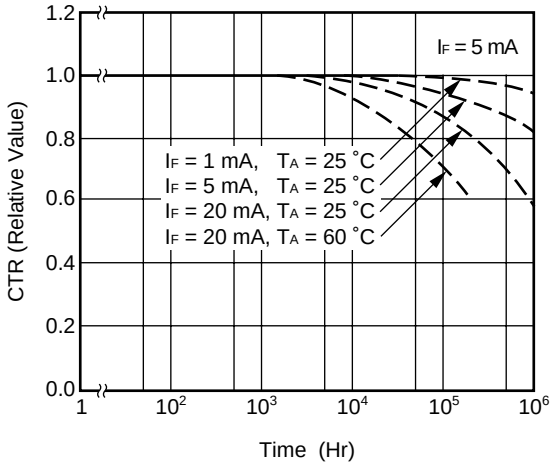
SWITCHING TIME vs. LOAD RESISTANCE



FREQUENCY RESPONSE



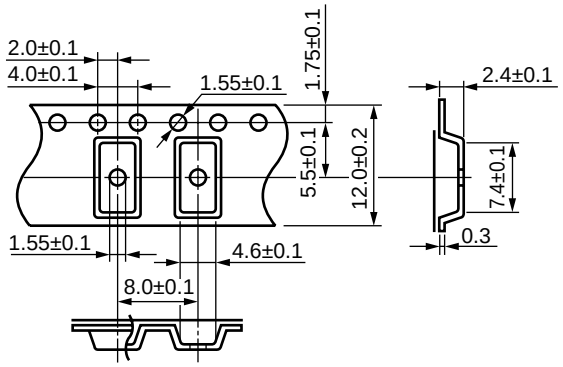
LONG TERM CTR DEGRADATION



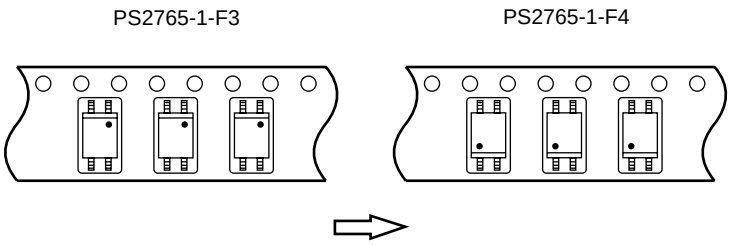
Remark The graphs indicate nominal characteristics.

TAPING SPECIFICATIONS (in millimeters)

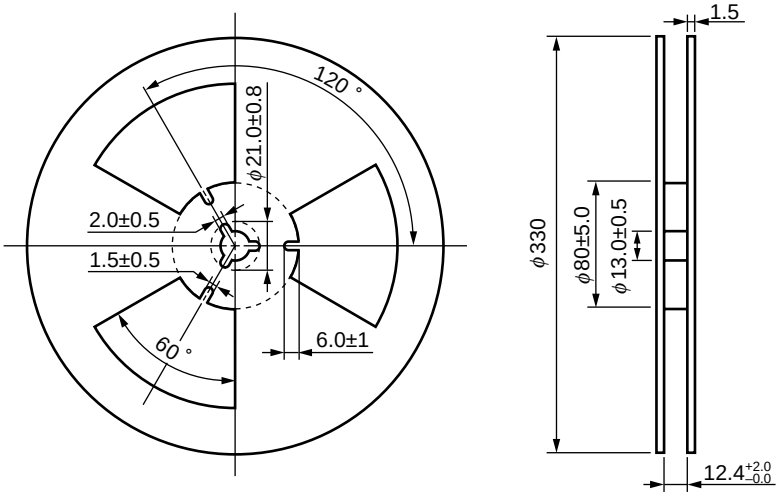
Outline and Dimensions (Tape)



Tape Direction



Outline and Dimensions (Reel)



Packing: 3 500 pcs/reel

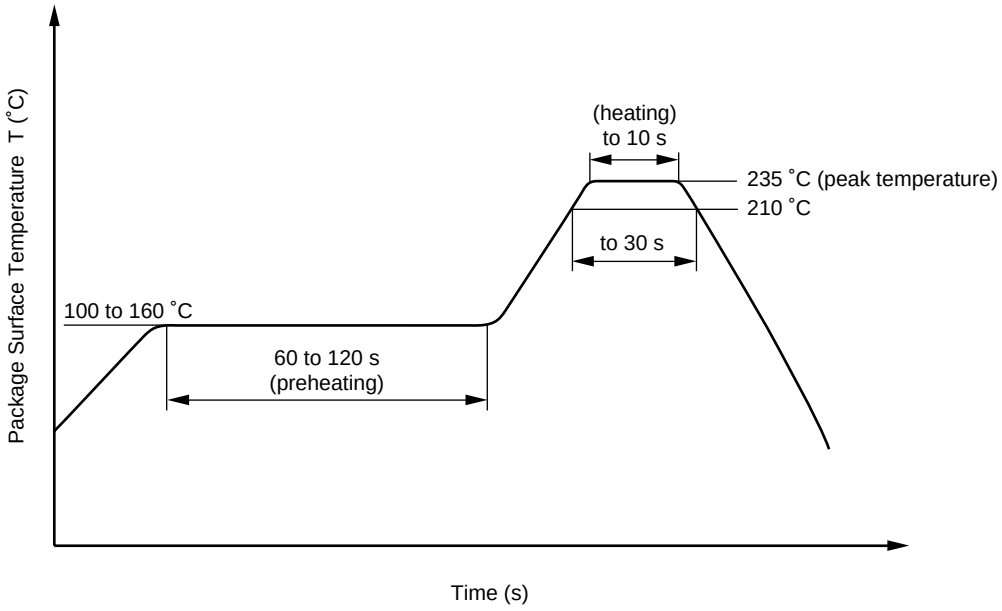
NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

- Peak reflow temperature — 235 °C or below (package surface temperature)
- Time of temperature higher than 210 °C — 30 seconds or less
- Number of reflows — Three
- Flux — Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Dip soldering

- Temperature — 260 °C or below (molten solder temperature)
- Time — 10 seconds or less
- Number of times — One (Allowed to be dipped in solder including plastic mold portion.)
- Flux — Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

(3) Cautions

- Fluxes

  Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between corrector-emitters at startup, the output side may enter the on state, even if the voltage is within the absolute maximum ratings.

[MEMO]

[MEMO]

[MEMO]

CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

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M8E 00.4